

YJ Planar Schottky Barrier Diode Die Specification

150V 20A, 108mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB108H150AS-280A

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 20 \text{ A}$

2%

Device Schematics and Outline Drawing

Die Thickness *

Die Size **

Top Metal Pad

Active Area

Top Metal

Back Metal

Note: 1 * : Also can offer device with 8 mils thickness

2 **: Cutting street width is around 1.5 mils

Important Notice

Specification apply to die only. Actual performance may degrade when assembled.